捷多邦,专业PCB打样工厂,24小时加急出货





5-V Low-Drop Voltage Regulator

TLE 4263

Features			
• Output vo	Solution of the second state of the second st	COM	
• 200 mA o	utput current capability		
Low-drop	voltage		
• Very low	standby current consum	nption	13.60
Overtemp	perature protection		P-DSO-14-8
Reverse	polarity protection		Brink, DZSC.60
• Short-circ	uit proof		WWWW
 Adjustable 	e reset threshold		
Watchdog			
• Wide tem	perature range		
Suitable f	or use in automotive ele	ectronics	
-188	p.		

туре	ordering oode	Гаскаде
TLE 4263 GM	Q67006-A9357-A201K5	P-DSO-14-8

SMD type

Functional Description

TLE 4263 is a 5-V low-drop voltage regulator in a P-DSO-14-8 SMD package. The maximum input voltage is 45 V. The maximum output current is more than 200 mA. The IC is short-circuit proof and incorporates temperature protection which turns off the IC at overtemperature.

The IC regulates an input voltage V_1 in the range of 6 V < V_1 < 45 V to $V_{Q,nom}$ = 5.0 V. A reset signal is generated for an output voltage of $V_{Q,n}$ < 4.5 V. This voltage threshold can be decreased to 3.5 V by external connection of a voltage divider. The reset delay can be set externally by a capacitor. The integrated watchdog logic supervises the connected microcontroller. The IC can be switched off via the inhibit input, which causes the current consumption to drop from 900 μ A to typical 0 μ A.





Choosing External Components

The input capacitor C_1 is necessary for compensation of line influences. Using a resistor of approx. 1 Ω in series with C_1 , the oscillating circuit consisting of input inductivity and input capacitance can be damped. The output capacitor is necessary for the stability of the regulating circuit. Stability is guaranteed at values $\geq 22 \ \mu$ F and an ESR of $\leq 3 \Omega$ within the operating temperature range. For small tolerances of the reset delay the spread of the capacitance of the delay capacitor and its temperature coefficient should be noted.

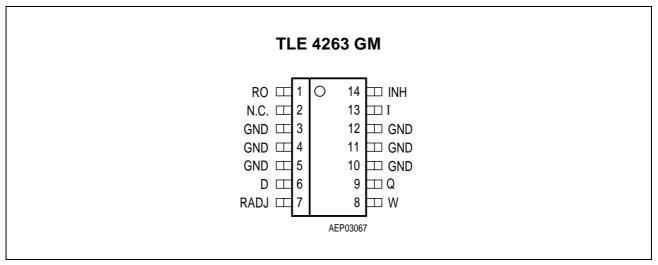


Figure 1 Pin Configuration (top view)



Pin (P-DSO-14-4)	Symbol	Function
1	RO	Reset output; open-collector output connected to the output via a resistor of 30 k Ω .
2	N.C.	Not connected
3 - 5, 10 - 12	GND	Ground
6	D	Reset delay; connected to ground with a capacitor.
7	RADJ	Reset threshold; to adjust the switching threshold connect a voltage divider (output to GND) to the pin. If this input is connected to GND, reset is triggered at an output voltage of 4.5 V.
8	W	Watchdog; rising edge triggered input for monitoring a microcontroller.
9	Q	5-V output voltage; block to ground with a capacitor, $C \ge 22 \ \mu F$, ESR $\le 3 \ \Omega$ at
13	1	Input voltage; block to ground directly at the IC with a ceramic capacitor.
14	INH	Inhibit; TTL-compatible, low-active input.

Pin Definitions and Functions



Circuit Description

The control amplifier compares a reference voltage, which is kept highly accurate by resistance adjustment, to a voltage that is proportional to the output voltage and drives the base of the series transistor via a buffer. Saturation control as a function of the load current prevents any over-saturation of the power element. If the externally scaled down output voltage at the reset threshold input drops below 1.35 V, the external reset delay capacitor is discharged by the reset generator. When the voltage of the capacitor reaches the lower threshold V_{DRL} , a reset signal occurs at the reset output and is held until the upper threshold V_{DRL} , a reset signal occurs at the reset output and is held until the upper threshold V_{DU} is exceeded. If the reset threshold input is connected to GND, reset is triggered at an output voltage of typ. 4.65 V. A connected microcontroller will be monitored through the watchdog logic. In case of missing pulses at pin W, the reset output is set to low. The pulse sequence time can be set in a wide range with the reset delay capacitor. The IC can be switched at the TTL-compatible, low-active inhibit input. The IC also incorporates a number of internal circuits for protection against:

- Overload
- Overtemperature
- Reverse polarity

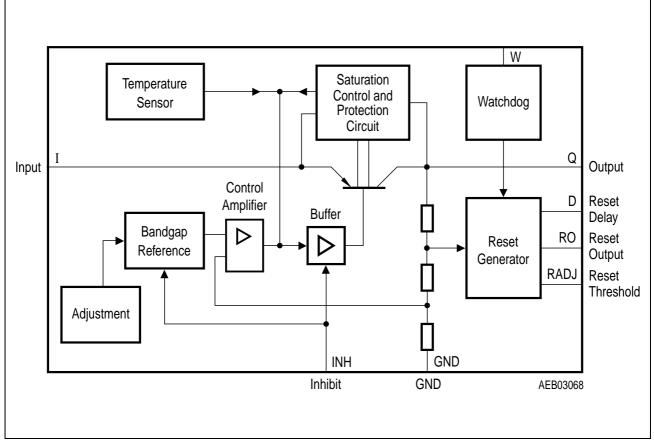


Figure 2 Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Lim	it Values	Unit	Remarks	
		min.	min. max.			
Input I						
Input voltage Input current	$V_1 I_1$	- 42 -	45 -	V _	– internally limited	
Reset Output RO						
Voltage Current	$V_{R} \ I_{R}$	- 0.3 -	42 -	V -	– internally limited	
Reset Threshold RA	DJ					
Voltage	$V_{\scriptscriptstyle RADJ}$	- 0.3	6	V	_	
Reset Delay D						
Voltage Current	$V_{ m D}$ $I_{ m D}$	- 0.3 -	42 -	V _	– internally limited	
Output Q						
Voltage Current	V_{Q} I_{Q}	- 0.3 -	7 -	V _	– internally limited	
Inhibit INH						
Voltage	V_{INH}	- 42	45	V	_	
Watchdog W				_		
Voltage	V_{W}	- 0.3	6	V	_	
Ground GND	·					
Current	$I_{\rm GND}$	- 0.5	_	А	_	



Absolute Maximum Ratings (cont'd)

Parameter	Symbol	Lim	it Values	Unit	Remarks
		min.	max.		
Temperature					
Junction temperature	T_{j}	_	150	°C	_
Storage temperature	$T_{ m stg}$	- 50	150	°C	-
Operating Range					
Input voltage	V_1	_	45	V	_
Junction temperature	Tj	- 40	150	°C	-
Thermal resistance					
junction-ambient	$R_{ m thj-a}$	-	112	K/W	1)
junction-pin	$R_{ m thj-p}$	_	32	K/W	2)

 $^{1)}$ Package mounted on PCB 80 \times 80 \times 1.5mm^3; 35 μ Cu; 5 μ Sn; Footprint only; zero airflow. Package mounted on PCB 80 \times 80 \times 1.5mm^3; 35 μ Cu; 5 μ Sn; Footprint only; zero airflow.



Characteristics

 $V_{\rm I}$ = 13.5 V; - 40 °C < $T_{\rm j}$ < 125 °C; $V_{\rm INH}$ > 3.5 V; (unless specified otherwise)

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		

Normal Operation

V_{Q}	4.90	5.00	5.10	V	5 mA \leq $I_{\text{Q}} \leq$ 150 mA; 6 V \leq $V_{\text{I}} \leq$ 28 V
V _Q	4.90	5.00	5.10	V	$6 V \le V_1 \le 32 V;$ $I_Q = 100 mA;$ $T_j = 100 °C$
I _Q	200	250	_	mA	1)
Iq	-	0	50	μA	$V_{\rm INH} = 0$
I.	_	900	1300	μA	$I_{0} = 0 \text{ mA}$
	_			-	$I_0 = 150 \text{ mA}$
I _q	-	15	23	mA	$I_{\rm Q} = 150 \text{ mA}; V_{\rm I} = 4.5 \text{ V}$
$V_{ m dr}$	_	0.35	0.50	V	$I_{\rm Q} = 150 \ {\rm mA}^{1)}$
$\Delta V_{ m Q,lo}$	_	-	25	mV	$I_{\rm Q}$ = 5 mA to 150 mA
$\Delta V_{Q.li}$	-	3	25	mV	$V_{I} = 6 \text{ V to } 28 \text{ V;}$ $I_{Q} = 150 \text{ mA}$
PSRR	-	54	-	dB	$f_{\rm r}$ = 100 Hz; $V_{\rm r}$ = 0.5 $V_{\rm PP}$
	V_{Q} I_{Q} I_{q} I_{q} I_{q} I_{q} V_{dr} $\Delta V_{Q,lo}$ $\Delta V_{Q,li}$	$\begin{array}{c} V_{\rm Q} & 4.90 \\ \hline \\ I_{\rm Q} & 200 \\ \hline \\ I_{\rm q} & - \\ V_{\rm dr} & - \\ \hline \\ \Delta V_{\rm Q,lo} & - \\ \Delta V_{\rm Q,li} & - \\ \end{array}$	$V_{\rm Q}$ 4.905.00 $I_{\rm Q}$ 200250 $I_{\rm q}$ -0 $I_{\rm q}$ -900 $I_{\rm q}$ -10 $I_{\rm q}$ -15 $V_{\rm dr}$ -0.35 $\Delta V_{\rm Q,lo}$ $\Delta V_{\rm Q,li}$ -3	$V_{\rm Q}$ 4.905.005.10 $I_{\rm Q}$ 200250- $I_{\rm q}$ -050 $I_{\rm q}$ -9001300 $I_{\rm q}$ -1018 $I_{\rm q}$ -0.350.50 $V_{\rm dr}$ 25 $\Delta V_{\rm Q,lo}$ -325	$V_{\rm Q}$ 4.905.005.10V $I_{\rm Q}$ 200250-mA $I_{\rm q}$ -050 μ A $I_{\rm q}$ -9001300 μ A $I_{\rm q}$ -1012mA $I_{\rm q}$ -0.350.50V $\Delta V_{\rm Q,lo}$ 25mV $\Delta V_{\rm Q,li}$ -325mV

Reset Generator

Switching threshold	$V_{ m Q,rt}$	4.5	4.65	4.8	V	$V_{\text{RADJ}} = 0 \text{ V}$
Reset adjust threshold	$V_{ m RADJ,th}$	1.26	1.35	1.44	V	V _Q > 3.5 V
Reset low voltage	$V_{ m RO,I}$	_	0.10	0.40	V	$I_{\rm RO}$ = 1 mA

Note: The reset output is low within the range $V_{\rm Q}$ = 1 V to $V_{\rm Q,rt}$

¹⁾ Drop voltage = $V_i - V_q$ (measured when the output voltage has dropped 100 mV from the nominal value obtained at 6 V input)



Characteristics (cont'd)

 $V_{\rm I}$ = 13.5 V; – 40 °C < $T_{\rm j}$ < 125 °C; $V_{\rm INH}$ > 3.5 V; (unless specified otherwise)

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Saturation voltage	$V_{\scriptscriptstyle D,sat}$	_	50	100	mV	$V_{\rm Q}$ < $V_{\rm R,th}$
Upper timing threshold	$V_{ m DU}$	1.45	1.70	2.05	V	-
Lower reset timing threshold	$V_{ m drl}$	0.20	0.35	0.55	V	_
Charge current	$I_{D,ch}$	40	60	85	μA	-
Reset delay time	t _{rd}	1.3	2.8	4.1	ms	<i>C</i> _D = 100 nF
Reset reaction time	t _{rr}	0.5	1.2	4	μS	<i>C</i> _D = 100 nF

Watchdog

Discharge current	$I_{\mathrm{D,wd}}$	4.40	6.25	9.10	μA	$V_{\rm D}$ = 1.0 V
Upper timing threshold	$V_{ m DU}$	1.45	1.70	2.05	V	_
Lower timing threshold	$V_{\rm DWL}$	0.20	0.35	0.55	V	_
Watchdog trigger time	$T_{ m WI,tr}$	16	22.5	27	ms	C _D = 100 nF

Inhibit

Switching voltage	$V_{\rm INH,ON}$	3.6	_	_	V	IC turned on
Turn-OFF voltage	$V_{\mathrm{INH,OFF}}$	-	_	0.8	V	IC turned off
Input current	I _{INH}	5	10	25	μA	$V_{\text{INH}} = 5 \text{ V}$

Note: The reset output is low within the range $V_{\rm Q}$ = 1 V to $V_{\rm Q,rt}$



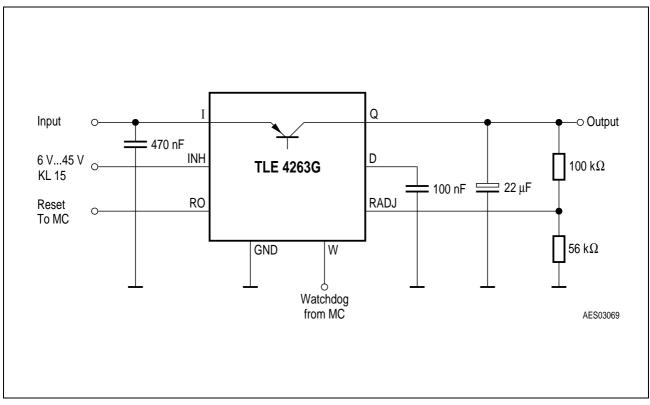


Figure 3 Application Circuit

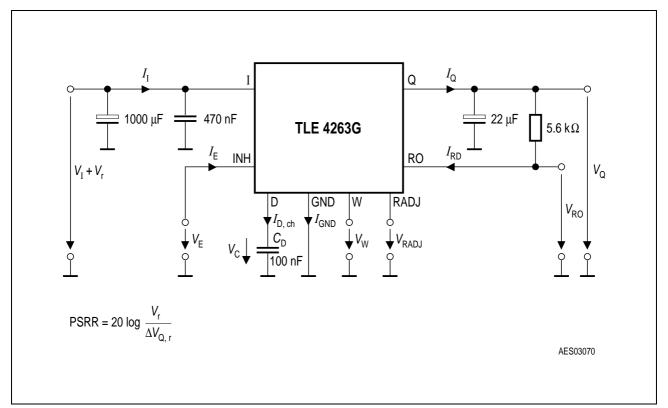


Figure 4 Test Circuit



Reset Timing

The power-on reset delay time is defined by the charging time of an external capacitor C_{D} which can be calculated as follows:

 $C_{\rm D}$ = ($t_{\rm rd} \times I_{\rm D,ch}$)/ ΔV

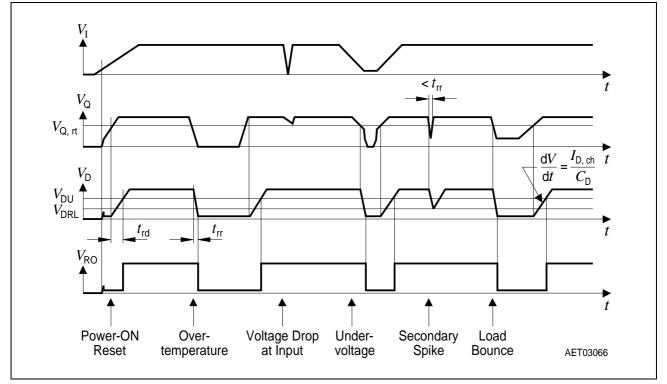
Definitions:

 $C_{\rm D}$ = delay capacitor $t_{\rm rd}$ = reset delay time

 $I_{\text{D,ch}}$ = charge current, typical 60 μ A

 $\Delta V = V_{\text{DU}}$, typical 1.70 V

 V_{DU} = upper delay switching threshold at C_{D} for reset delay time





Reset Switching Threshold

The present default value is typ. 4.65 V. When using the TLE 4263 the reset threshold can be set to 3.5 V < $V_{Q,rt}$ < 4.6 V by connecting an external voltage divider to pin RADJ. The calculation can be easily done since the reset adjust input current can be neglected. If this feature is not needed, the pin has to be connected to GND.

$$V_{\text{Q, rt}} = (1 + R1/R2) \times V_{\text{RADJ,th}}$$



Definitions: $V_{Q,rt}$ = reset threshold $V_{RADJ, th}$ = comparator reference voltage, typical 1.35 V

Watchdog Timing

The frequency of the watchdog pulses has to be higher than the minimum pulse sequence which is set by the external reset delay capacitor C_{D} . Calculation can be done according to the formulas given in **Figure 6**.

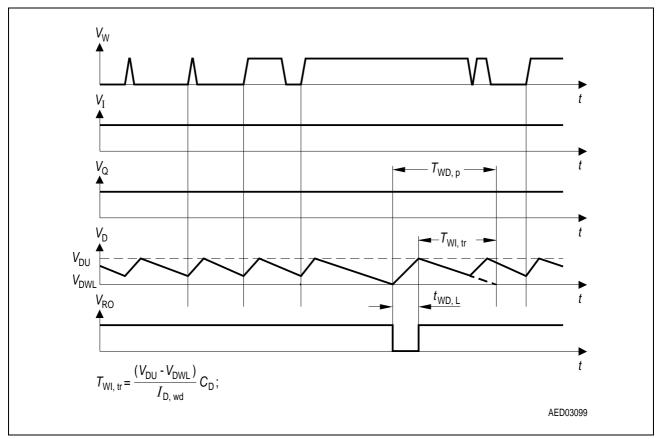
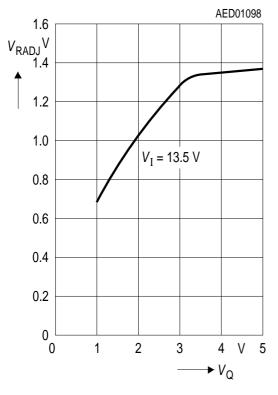


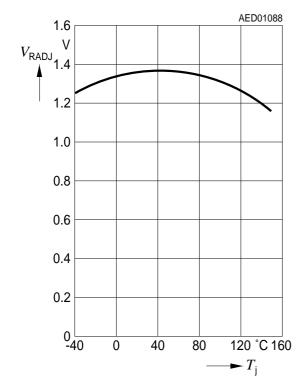
Figure 6 Timing of the Watchdog FunctionReset



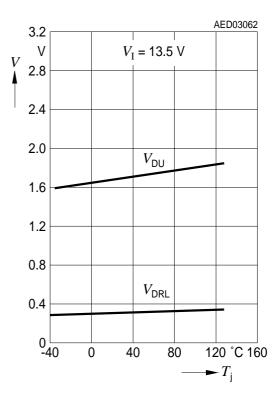
Reset Switching Threshold versus Output Voltage



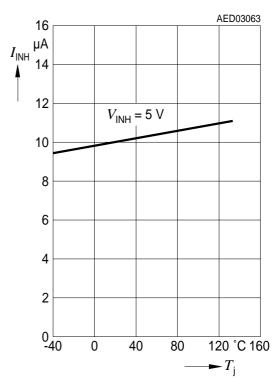
Reset Switching Threshold versus Temperature



Timing Threshold Voltage $V_{\rm DU}$ and $V_{\rm DRL}$ versus Temperature

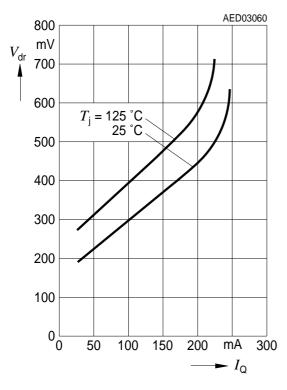


Current Consumption of Inhibit versus Temperature

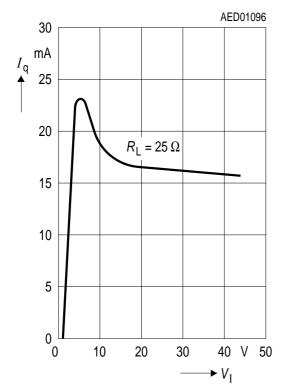




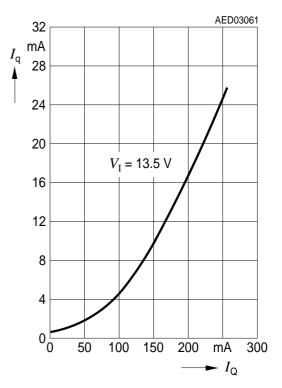
Drop Voltage versus OutputCurrent



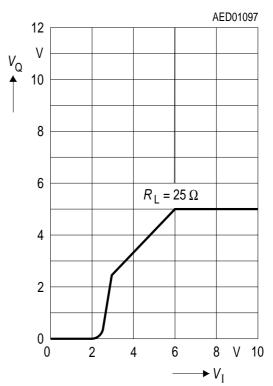
Current Consumption versus Input Voltage



Current Consumption versus Output Current

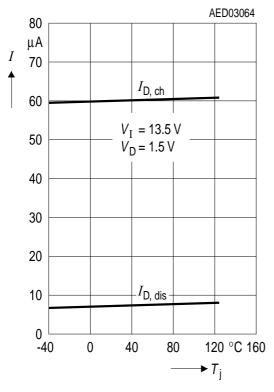


Output Voltage versus Input Voltage

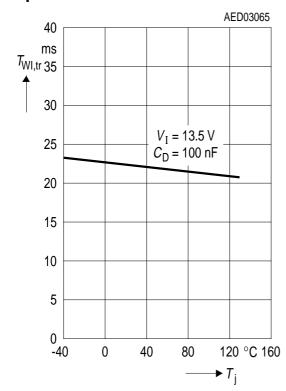




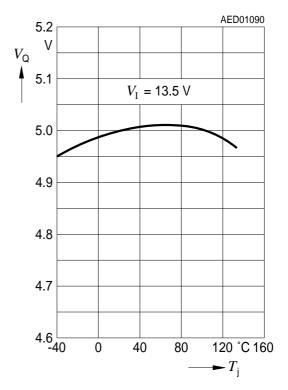
Charge Current and Discharge Current versus Temperature



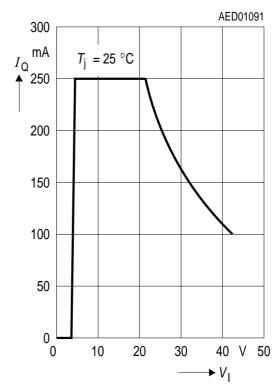
Pulse Time versus Temperature



Output Voltage versus Temperature

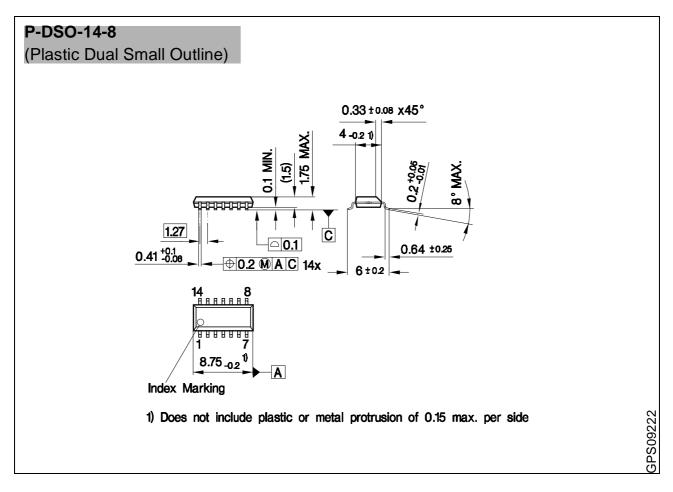


Output Current versus Input Voltage





Package Outlines



Sorts of Packing Package outlines for tubes, trays etc. are contained in our Data Book "Package Information". SMD = Surface Mounted Device

Dimensions in mm







Edition 2001-01-17

Published by Infineon Technologies AG, St.-Martin-Strasse 53, D-81541 München © Infineon Technologies AG1999. All Rights Reserved.

Attention please!

The information herein is given to describe certain components and shall not be considered as warranted characteristics.

Terms of delivery and rights to technical change reserved.

We hereby disclaim any and all warranties, including but not limited to warranties of noninfringement, regarding circuits, descriptions and charts stated herein.

Infineon Technologies is an approved CECC manufacturer.

Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office in Germany or our Infineon Technologies Representatives worldwide (see address list).

Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered. This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.